HT7L5610
Primary Side Regulation Off Line LED Driver with Active PFC

Features

- Primary-side current sensing and regulation without an opto-coupler
- Integrated 650V MOSFET
- Wide AC input range - from $85V_{AC}$ to $265V_{AC}$
- High Power Factor of >0.9 without additional circuitry
- Accurate constant current (< ±3%)
- Low start-up current which reduces power dissipation
- Full protection functions for enhanced safety
  - Gate driver output voltage clamp
  - VCC over voltage protection - VCC OVP
  - VCC under-voltage lockout with hysteresis - VCC UVLO
  - Output LED string over current protection
  - Output LED string short / open protection
  - On-chip over temperature protection - OTP
- 8-pin DIP package

Applications

- General illumination
- E26/27, T5/T8 LED Lamp
- Other LED Lighting Applications

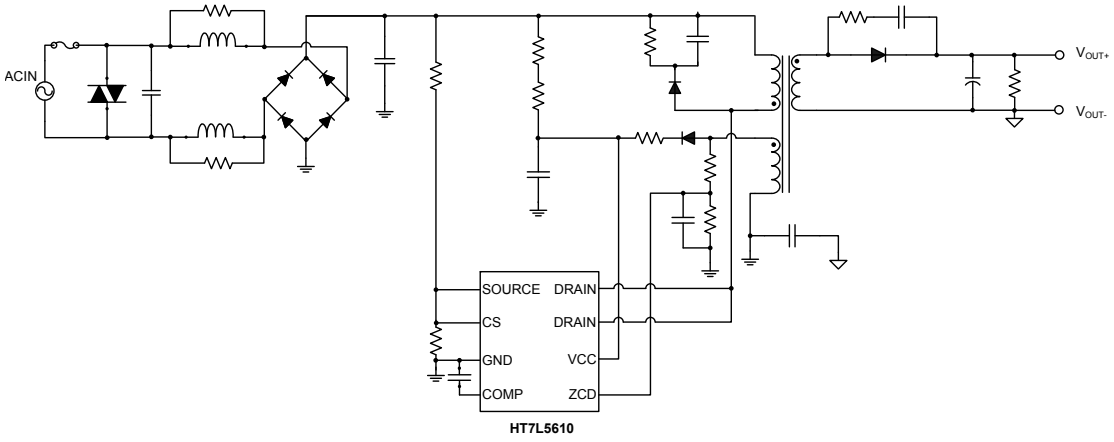
General Description

The HT7L5610 is a single-stage, isolated, primary-side offline LED lighting controller that has the benefits of high power factor and a fully integrated power MOSFET. Control of this power MOSFET is implemented by regulating a constant LED current accurately from the primary-side. This can significantly simplify the LED lighting system design by eliminating the secondary-side feedback components and the usually required opto-coupler. The extremely low start-up current and quiescent current reduces the total power consumption to provide a high efficiency solution for lighting applications.

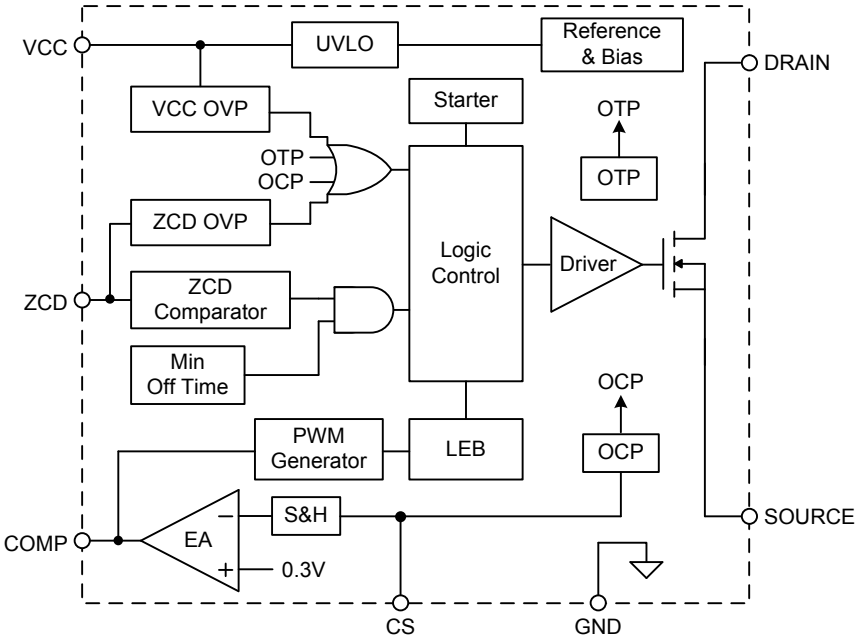
The device provides several protection functions, which include VCC Under Voltage Lockout (UVLO), Over Current Protection (OCP), Output LED String Open Protection, Output LED String Short Protection, VCC Over Voltage Protection (OVP) and Leading-Edge Blanking (LEB) for current sensing. Additionally and to ensure system reliability, the device includes a fully integrated thermal protection function.

The high level of functional integration minimises the external component count giving major advantages in terms of cost and circuit board area. The device is supplied in an 8-pin DIP package.

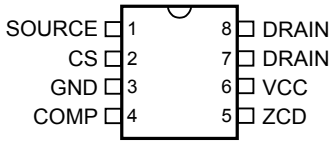
Application Circuits



Block Diagram



Pin Assignment



HT7L5610
8 DIP-A

Pin Description

Pin No.	Symbol	Description
1	SOURCE	Internal high voltage power MOSFET source terminal
2	CS	Current sense pin. A resistor is connected to sense the MOSFET current.
3	GND	Ground pin
4	COMP	Loop compensation pin. A capacitor is placed between COMP and GND.
5	ZCD	Connected to a resistor divider from an auxiliary winding to sense the output voltage.
6	VCC	Power supply pin
7,8	DRAIN	Internal high voltage power MOSFET drain terminal

Absolute Maximum Ratings

Parameter	Range
Internal MOSFET Drain Source Voltage	-0.3V to 650V
VCC Supply Voltage	-0.3V to 27V
Input Voltage to CS Pin	-0.3V to 6V
Output Voltage at COMP Pin	-0.3V to 6V
Maximum Current at ZCD Pin	3mA (source), 3mA (sink)
Maximum Operating Junction Temperature	150°C
Storage Temperature Range	-55°C to 150°C

Recommended Operating Ranges

Parameter	Range
VCC Supply Voltage	10V~20V
Operating Junction Temperature	-40°C~125°C
Output Power	13.8W@240mA, 90~265V_{AC} 21.8W@365mA,180~265V_{AC}

Electrical Characteristics

(V_{CC}=12V, Ta=25°C)

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
Power Supply (VCC Pin)						
VCC_{ON}	$UVLO_{ON}$	—	—	18	—	V
VCC_{OFF}	$UVLO_{OFF}$	—	—	7.5	—	V
VCC_{HYS}	UVLO Hysteresis	—	10	—	—	V
V_{OVP1}	VCC OVP Trip Point	—	21.5	24.0	26.5	V
I_{START}	Start-up Current	Before turn-on, @V_{CC}=$UVLO_{ON}$-1V	—	10	20	μA
I_Q	Quiescent Current	No switching	—	0.7	1.0	mA
Error Amplifier						
V_{FB}	Feedback Reference Voltage	Ta=25°C	291	300	309	mV
Current Sense Comparator						
t_{LEB}	Leading Edge Blanking Time	—	—	400	—	ns
V_{OCP}	Current Limit Threshold	—	—	1.55	—	V
V_{SCP}	ZCD Pin Short Circuit Protection Threshold	—	—	0.40	—	V
Zero Current Detector						
V_{ZCDH}	Upper Clamp Voltage	I_{ZCD}=2.5mA	—	6.1	—	V
V_{ZCDL}	Lower Clamp Voltage	I_{ZCD}= -2.5mA	—	-0.7	—	V
V_{ZCDA}	Positive-going Edge	—	—	150	—	mV
V_{ZCDT}	Negative-going Edge	—	—	50	—	mV
V_{OVP2}	ZCD pin OVP Level	—	2.88	3.20	3.52	V
t_{B_OVP}	OVP Detection Blanking Time	—	—	1	—	μs
Starter						
t_{START}	Start Timer Period	—	—	40	—	μs
t_{OFF}	Minimum Off Time	—	—	6.4	—	μs
Over Temperature Protection						
OTP	Over Temperature Trip Point	—	—	150	—	°C
Power MOSFET						
R_{DS}	Power MOSFET Switch ON Resistance	@ V_{GS}=10V, I_{DS}=0.5A	—	4.3	—	Ω
BV_{DSS}	Power MOSFET Drain-Source Voltage	@ V_{GS}=0V, I_{DS}<250μA	650	—	—	V

Typical Performance Characteristics

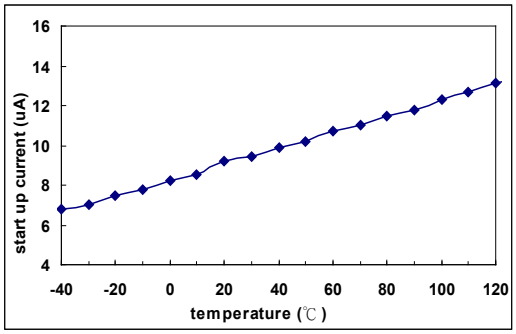


Figure 1. Start-up Current vs. Temperature

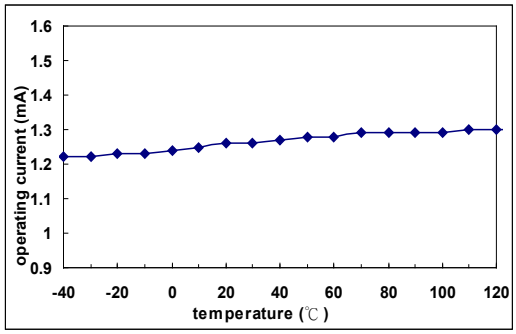


Figure 2. Operation Current vs. Temperature

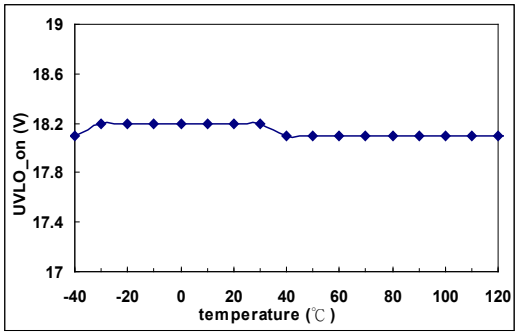


Figure 3. UVLO_on vs. Temperature

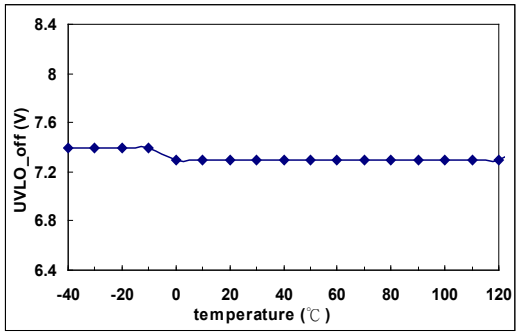


Figure 4. UVLO_off vs. Temperature

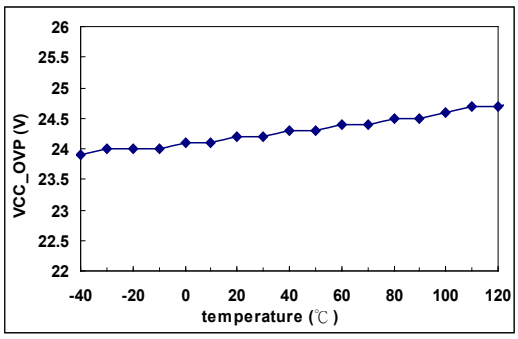


Figure 5. VCC_OVP vs. Temperature

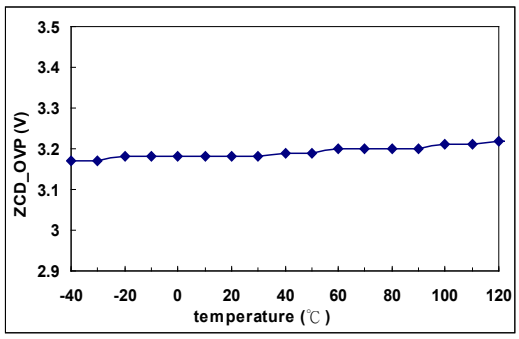


Figure 6. ZCD_OVP vs. Temperature

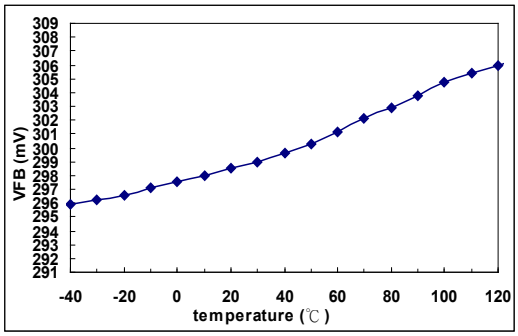


Figure 7. V_{FB} vs. Temperature

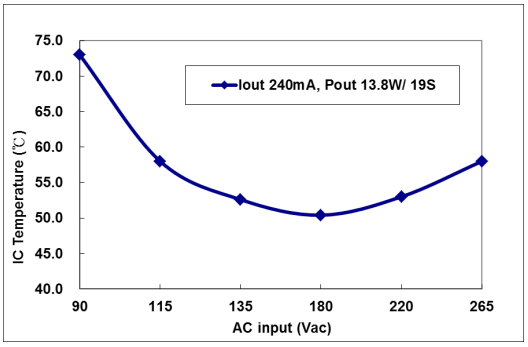


Figure 8. Temperature vs. Wide AC Voltage

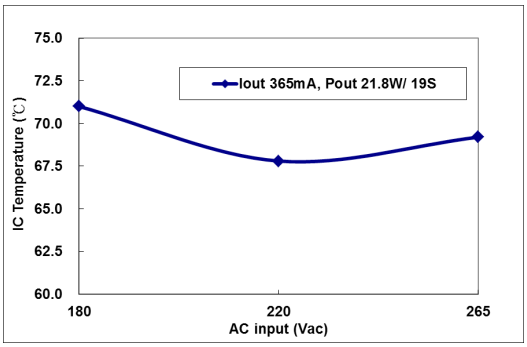


Figure 9. Temperature vs. High AC Voltage

Functional Description

The HT7L5610 is a single-stage primary-side offline LED controller designed for isolated LED lighting applications. The device can achieve high Power Factor values and low THD without resorting to additional external circuits and can also generate high accuracy LED drive currents with very few external components.

Start-up Current

A very low start-up current, I_{START}, allows the selection of a large value start-up resistor which reduces power dissipation.

Power Factor Correction

High power factor values are achieved by constant on-time operation. To implement constant on-time control, a 0.47μF capacitor is placed between the COMP pin and ground.

Constant Current Control

The device accurately regulates the LED current by sensing the primary-side information. The LED current can be easily set using the following formula:

$$I_{OUT} \approx \frac{1}{2} \times \frac{V_{FB}}{R_{CS}} \times \frac{N_P}{N_S}$$

Where N_P is the primary winding and N_S is the secondary winding; V_{FB} (=300mV) is the internal voltage reference and R_{CS} is the external current sensing resistor.

VCC Under Voltage Lockout – UVLO

The device includes a UVLO feature which has about 10V of hysteresis. The PWM controller turns on when VCC is higher than 18V and turns off when VCC is lower than 7.5V. The hysteresis characteristics guarantee that the device can be powered by an input capacitor during start-up. When the output voltage increases to a certain value after start-up, VCC will be charged by an output through an auxiliary winding.

Boundary Conduction Mode – BCM

The power MOSFET is turned on by inductor current zero-crossing detection. The current zero-crossing can be detected by a ZCD voltage. When the inductor current is at the zero crossing point, the voltage on the ZCD pin will drop rapidly. The HT7L5610 then detects the falling edge and turns on the Power MOSFET. The boundary conduction mode provides low turn-on switching losses and high conversion efficiency.

LEB on CS – Leading-Edge Blanking

Each time the internal power MOSFET is switched on, a turn-on spike will inevitably occur at the sense resistor. To avoid faulty triggering, a 400ns leading-edge blank time is generated. During this blanking period, the current-limit comparator is disabled and can therefore not switch off the gate driver.

OVP on VCC – Over Voltage Protection

In order to prevent PWM controller damage, the device includes an OVP function on VCC. Should the VCC voltage be higher than the OVP threshold voltage of 24V, the PWM controller will stop operating immediately. When the VCC voltage decreases below the UVLO off level, the controller will reset.

LED Open Protection – ZCD OVP

The ZCD pin voltage is set by a resistor divider, R_{TOP} (top resistor) and R_{BOT} (bottom resistor), and an auxiliary winding due to the coupling polarity between the auxiliary winding and the secondary winding of the transformer. Once the ZCD voltage exceeds 3.2V after a blanking time about 1μs to allow the leakage inductance ringing to be fully damped, the ZCD OVP is triggered and the IC stops switching. It can be reset by re-starting the voltage on VCC pin. The OVP voltage can be adjusted using the following equation:

$$V_{OUT_OVP} = 3.2 \times (1 + \frac{R_{TOP}}{R_{BOT}}) \times \frac{N_S}{N_A} + V_D$$

Where N_S is secondary winding, N_A is the auxiliary winding, V_D is the forward bias voltage of the secondary diode.

OCP – Over Current Protection

The device includes an over current protection function on the CS pin. An internal circuit detects the current level and when the current is larger than the over current protection threshold level, V_{OCP}/R_{CS}, the gate output will remain at a low level.

LED Short Protection – SCP

The output voltage drops when a number of LEDs in a string are shorted resulting in a voltage drop at VCC. Once the VCC drops below 7.5V, the device will stop operating. Under such situations, the start-up operation will recharge the VCC pin through the start-up resistor and the device will enter the UVLO hiccup mode.

Thermal Protection

A thermal protection feature is included to protect the device from excessive heat damage. When the junction temperature exceeds a threshold of 150°C, the thermal protection function will turn off the drain source terminal terminal immediately. When the VCC decreases below the UVLO off level, the controller will reset.

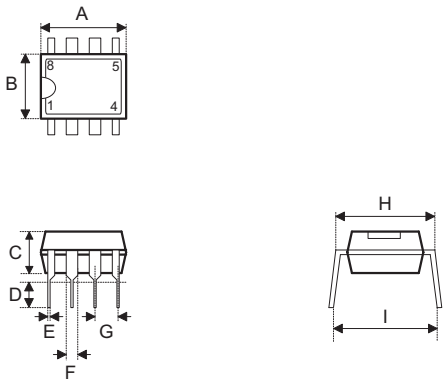
Package Information

Note that the package information provided here is for consultation purposes only. As this information may be updated at regular intervals users are reminded to consult the Holtek website for the latest version of the Package/Carton Information.

Additional supplementary information with regard to packaging is listed below. Click on the relevant section to be transferred to the relevant website page.

- Package Information (include Outline Dimensions, Product Tape and Reel Specifications)
- The Operation Instruction of Packing Materials
- Carton information

8-pin DIP (300mil) Outline Dimensions



Symbol	Dimensions in inch		
	Min.	Nom.	Max.
A	0.355	0.365	0.400
B	0.240	0.250	0.280
C	0.115	0.130	0.195
D	0.115	0.130	0.150
E	0.014	0.018	0.022
F	0.045	0.060	0.070
G	—	0.100 BSC	—
H	0.300	0.310	0.325
I	—	—	0.430

Symbol	Dimensions in mm		
	Min.	Nom.	Max.
A	9.02	9.27	10.16
B	6.10	6.35	7.11
C	2.92	3.30	4.95
D	2.92	3.30	3.81
E	0.36	0.46	0.56
F	1.14	1.52	1.78
G	—	2.54 BSC	—
H	7.26	7.87	8.26
I	—	—	10.92

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